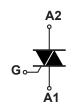
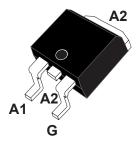


### 20 A - 800 V - 150 °C 8H Triac in D2PAK







D<sup>2</sup>PAK

# Product status link

T2035H-8G

Product summary		
I <sub>T(RMS)</sub>	20 A	
$V_{DRM}/V_{RRM}$	800 V	
V <sub>DSM</sub> /V <sub>RSM</sub>	900 V	
I <sub>GT</sub>	35 mA	
T <sub>j</sub> max.	150 °C	

#### **Features**

- 20 A high current Triac
- 800 V symmetrical blocking voltage
- 150 °C maximum junction temperature T<sub>i</sub>
- · Three triggering quadrants
- High noise immunity static dV / dt
- Robust dynamic turn-off commutation (dl/dt)c
- ECOPACK2 compliant component

#### **Applications**

- Home automation Smart AC plug
- Water heater, room heater and coffee machine
- AC Induction and Universal Motor control
- · Inrush current limiter in AC DC rectifiers
- Lighting and automation I/O control
- · General purpose AC line load control

#### **Description**

Specifically designed to operate at 800 V and 150 °C, the T2035H-8G Triac housed in D²PAK provides an enhanced thermal management: this 20 A Triac is the right choice for a compact drive of heavy AC loads and enables the heatsink size reduction.

Based on the ST Snubberless high temperature technology, it offers higher specified turn off commutation and noise immunity levels up to the  $T_i$  max.

The T2035H-8G safely optimizes the control of the hardest universal motors, heaters and inductive loads for industrial control and home appliances.



### 1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Parameter		
I <sub>T(RMS)</sub>	RMS on-state current (full sine wave)	T <sub>c</sub> = 128 °C	20	Α
<b>I</b>	Non repetitive surge peak on-state current (full cycle,	t = 16.7 ms	210	^
I <sub>TSM</sub>	T <sub>j</sub> initial = 25 °C)	t = 20 ms	200	Α
l <sup>2</sup> t	I <sup>2</sup> t value for fusing	t <sub>p</sub> = 10 ms	264	A <sup>2</sup> s
dl/dt	Critical rate of rise of on-state current, I <sub>G</sub> = 2 x I <sub>GT</sub> , tr ≤ 100 ns, f = 100 Hz	100	A/µs	
V <sub>DRM</sub> /V <sub>RRM</sub>	Repetitive peak off-state voltage	800	V	
V <sub>DSM</sub> /V <sub>RSM</sub>	Non Repetitive peak off-state voltage $t_p$ = 10 ms, $T_j$ = 25 °C		900	V
I <sub>GM</sub>	Peak gate current		4	Α
P <sub>GM</sub>	$t_p$ = 20 μs, $T_j$ = 150 °C Maximum gate power dissipation		5	W
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 150  ^{\circ}\text{C}$		1	W
T <sub>stg</sub>	Storage temperature range	-40 to +150	°C	
Tj	Operating junction temperature range	-40 to +150	°C	

Table 2. Electrical characteristics ( $T_j$  = 25 °C, unless otherwise specified)

Symbol	Test conditions	Quadrants		Value	Unit	
$V_D$ = 12 V, $R_L$ = 30 $\Omega$			1 - 11 - 111	Min.	5	mA
I <sub>GT</sub>	$V_D = 12 \text{ V}, R_L = 30 \Omega$		1 - 11 - 111	Max.	35	mA
V <sub>GT</sub>	$V_D = 12 \text{ V}, R_L = 30 \Omega$		1 - 11 - 111	Max.	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$		1 - 11 - 111	Min.	0.15	V
1.	I <sub>L</sub> I <sub>G</sub> = 1.2 x I <sub>GT</sub>		I - III	Max.	50	mA
'L			II	Max.	80	mA
I <sub>H</sub> <sup>(1)</sup>	I <sub>T</sub> = 500 mA, gate open			Max.	35	mA
dV/dt (1)	V <sub>D</sub> = 536 V, gate open	T <sub>j</sub> = 150 °C	Min.	2000	V/µs	
(dl/dt)c (1)	Without snubber network	T <sub>j</sub> = 150 °C	Min.	20	A/ms	

<sup>1.</sup> For both polarities of A2 referenced to A1.

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**Table 3. Static characteristics** 

Symbol	Test conditions	Tj		Value	Unit
V <sub>TM</sub> <sup>(1)</sup>	$I_{TM}$ = 28 A, $t_p$ = 380 $\mu$ s	25 °C	Max.	1.55	V
V <sub>TO</sub> <sup>(1)</sup>	Threshold voltage	150 °C	Max.	0.8	V
R <sub>D</sub> <sup>(1)</sup>	Dynamic resistance	150 °C	Max.	19	mΩ
	$V_D = V_R = V_{DRM} = V_{RRM}$	25 °C	Max.	2	μA
I <sub>DRM</sub> /I <sub>RRM</sub>	VD - VR - VDRM - VRRM	150 °C	IVIAX.	6.5	mA
	V <sub>D</sub> = V <sub>R</sub> = 400 V, peak voltage	150 °C	Max.	2.8	mA

<sup>1.</sup> For both polarities of A2 referenced to A1.

Table 4. Thermal resistance

Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub>	Junction to case (AC)	Max.	1.0	°C/W
R <sub>th(j-a)</sub>	Junction to ambient (S <sub>CU</sub> <sup>(1)</sup> = 2 cm <sup>2</sup> )	Тур.	45	°C/W

<sup>1.</sup> Scu: copper pad surface under tab, 35 μm copper thickness on FR4 PCB.



#### 1.1 Characteristics (curves)

Figure 1. Maximum power dissipation versus on-state RMS current

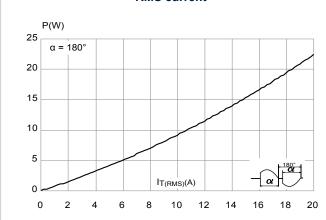


Figure 2. On-state RMS current versus case temperature

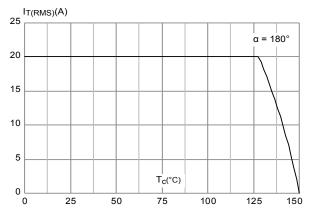


Figure 3. On-state RMS current versus ambient temperature (free air convection)

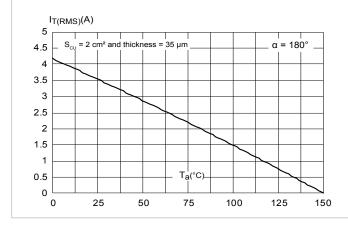


Figure 4. On-state characteristics (maximum values)

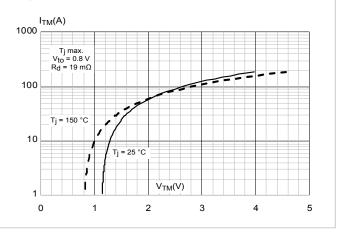


Figure 5. Relative variation of thermal impedance versus pulse duration

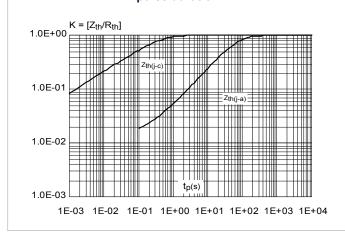
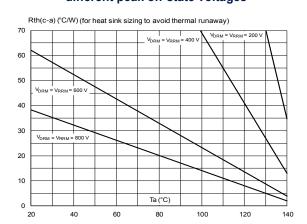


Figure 6. Recommended maximum case-to-ambient thermal resistance versus ambient temperature for different peak off-state voltages



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Figure 7. Thermal resistance junction to ambient versus copper surface under tab

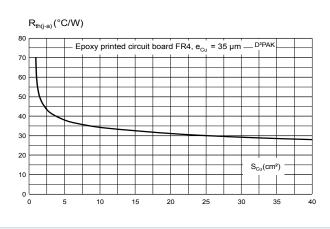


Figure 8. Relative variation of leakage current versus junction temperature for different values of blocking voltage

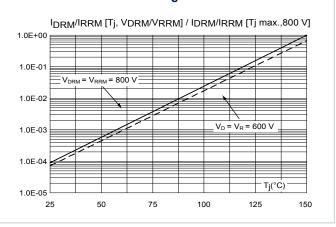


Figure 9. Relative variation of gate trigger voltage and current versus junction temperature (typical values)

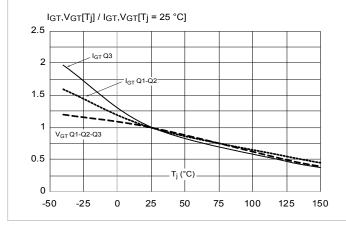


Figure 10. Relative variation of holding current and latching current versus junction temperature (typical values)

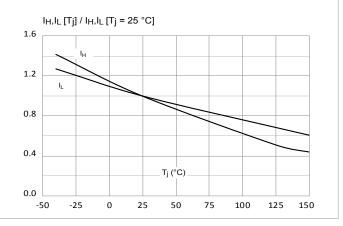


Figure 11. Surge peak on-state current versus number of cycles

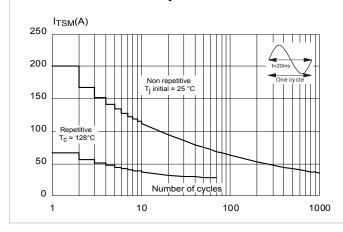
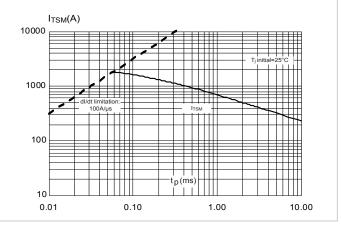


Figure 12. Non repetitive surge peak on-state current for a sinusoidal pulse with width  $t_{\rm p} < 10~{\rm ms}$ 



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Figure 13. Relative variation of static dV/dt immunity versus junction temperature

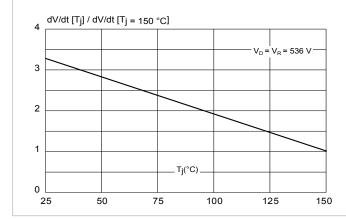
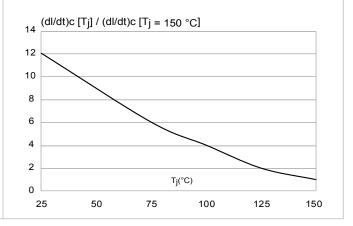


Figure 14. Relative variation of critical rate of decrease of main current versus junction temperature



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## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

### 2.1 D<sup>2</sup>PAK package information

- ECOPACK2 compliant
- · Lead-free package leads finishing
- Molding compound resin is halogen-free and meets UL94 flammability standard level V0

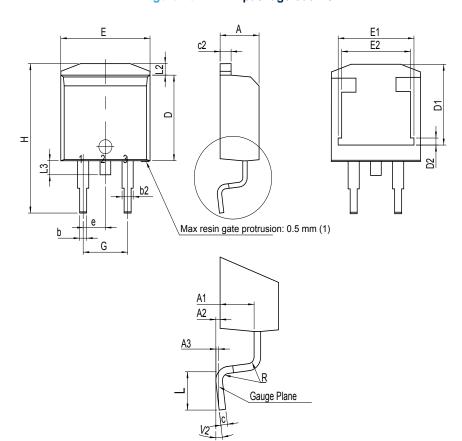


Figure 15. D<sup>2</sup>PAK package outline

(1) Resin gate is accepted in each of position shown on the drawing, or their symmetrical.

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Table 5. D<sup>2</sup>PAK package mechanical data

		Dimensions					
Ref.		Millimeters		Inches <sup>(1)</sup>			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.30		4.60	0.1693		0.1811	
A1	2.49		2.69	0.0980		0.1059	
A2	0.03		0.23	0.0012		0.0091	
A3		0.25			0.0098		
b	0.70		0.93	0.0276		0.0366	
b2	1.25		1.7	0.0492		0.0669	
С	0.45		0.60	0.0177		0.0236	
c2	1.21		1.36	0.0476		0.0535	
D	8.95		9.35	0.3524		0.3681	
D1	7.50		8.00	0.2953		0.3150	
D2	1.30		1.70	0.0512		0.0669	
е	2.54			0.10000			
Е	10.00		10.28	0.3937		0.4047	
E1	8.30		8.70	0.3268		0.3425	
E2	6.85		7.25	0.2697		0.2854	
G	4.88		5.28	0.1921		0.2079	
Н	15		15.85	0.5906		0.6240	
L	1.78		2.28	0.0701		0.0898	
L2	1.19		1.40	0.0468		0.0551	
L3	1.40		1.75	0.0551		0.0689	
R		0.40			0.0157		
V2 <sup>(2)</sup>	0°		8°	0°		8°	

<sup>1.</sup> Dimensions in inches are given for reference only

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<sup>2.</sup> Degrees



Figure 16. D<sup>2</sup>PAK recommended footprint (dimensions are in mm)

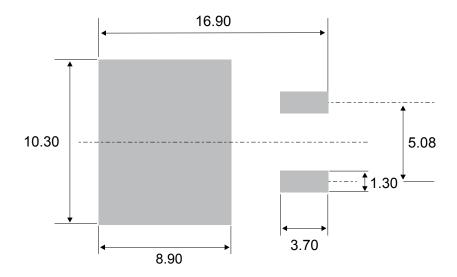
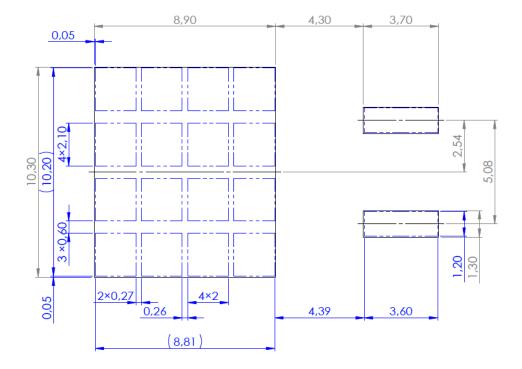


Figure 17. D<sup>2</sup>PAK stencil definitions (dimensions are in mm)



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# 3 Ordering information

Figure 18. Ordering information scheme

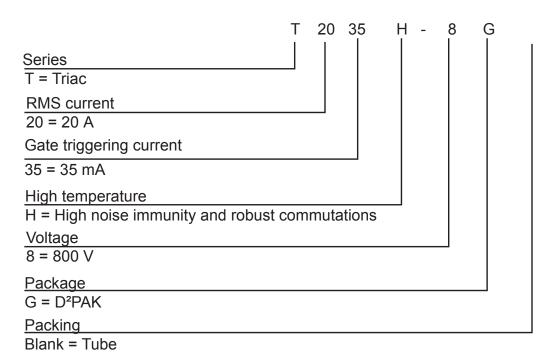


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode	
T2035H-8G-TR	T2035H-8G	D2DAK	D²PAK	DAK 16.0	1000	Tape and reel 13"
T2035H-8G	1203311-00	DIFAR	1.6 g	50	Tube	

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# **Revision history**

Table 7. Document revision history

Date	Version	Changes
21-Nov-2019	1	Initial release.
19-Feb-2020	2	Updated Table 2 and Table 3.
21-Dec-2020	3	Updated general description and Table 6. Inserted STPOWER logo.



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